# SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

# **ESD Protection Diode Array,** 5-Line

This 5-line surge protection array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-88 package.

#### **Features**

- Protects up to 5-Line in a Single SC-88 Package
- Peak Power Dissipation 100 W (8 x 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- Flammability Rating of UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available\*

#### **Applications**

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P <sub>PK</sub> 1	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1)	100	W
T <sub>J</sub>	Operating Junction Temperature Range	-40 to 125	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
T <sub>L</sub>	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 15000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



## ON Semiconductor®

www.onsemi.com

# SC-88 FIVE SURGE PROTECTION 100 W PEAK POWER



SC-88 CASE 419B STYLE 24

#### **PIN ASSIGNMENT**



- PIN1. CATHODE
  - 2. ANODE
  - 3. CATHODE
  - 4. CATHODE
  - 5. CATHODE 6. CATHODE

## MARKING DIAGRAM



XX = Specific Device Code

6J = SMF05C

6K = SZSMF12C/SMF12C

6L = SMF15C

6M = SMF24C

I = Date Code

= Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

<sup>1.</sup> Nonrepetitive current pulse per Figure 3.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

# SMF05CT1G ELECTRICAL CHARACTERISTICS ( $T_J = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 3)	6.2		7.2	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5 V		0.07	5.0	μΑ
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5 A (8 x 20 μs Waveform)			9.8	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 8 A (8 x 20 μs Waveform)			12.5	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			8.0	Α
Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)		80	130	pF

## SMF12CT1G ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	$V_{RWM}$	(Note 2)			12	٧
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1 mA, (Note 3)	13.3		15	٧
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 12 V		0.01	0.1	μΑ
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 3 A (8 x 20 μs Waveform)			21	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 6 A (8 x 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			6.0	Α
Capacitance	СЈ	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)		40	60	pF

# $\textbf{SMF15CT1G ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}C, \ unless \ otherwise \ specified)$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			15	V
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1 mA, (Note 3)	17		19	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 15 V		0.01	1.0	μΑ
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1 A (8 x 20 μs Waveform)			23	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5 A (8 x 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			5.0	Α
Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)		33	45	pF

# SMF24CT1G ELECTRICAL CHARACTERISTICS ( $T_J = 25^{\circ}C$ , unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			24	V
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1 mA, (Note 3)	26.7		32	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 24 V		0.01	1.0	μА
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1 A (8 x 20 μs Waveform)			40	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 2.5 A (8 x 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			2.5	Α
Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)		21	25	pF

<sup>2.</sup> Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

<sup>4.</sup> Include SZ-prefix devices where applicable.

# SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

#### **TYPICAL PERFORMANCE CURVES**

(T<sub>J</sub> = 25°C unless otherwise specified)

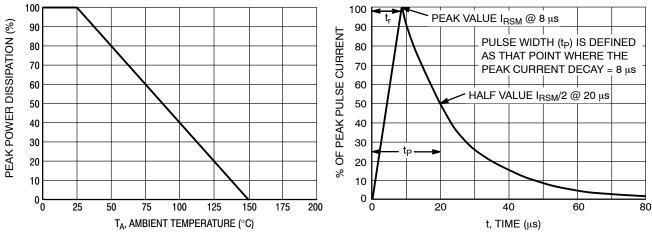


Figure 1. Pulse Derating Curve

Figure 2.  $8 \times 20~\mu s$  Pulse Waveform

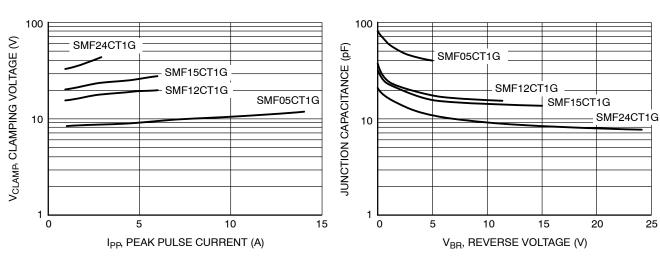


Figure 3. Clamping Voltage vs Peak Pulse Current

Figure 4. Junction Capacitance vs Reverse Voltage

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
SMF05CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF05CT2G*	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF12CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF15CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF24CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel

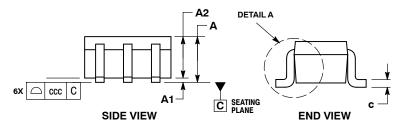
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>The "T2" suffix refers to an alternate tape & reel orientation.

#### SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y**

**DATE 11 DEC 2012** 





# NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS
- CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H. DATUMS A AND B ARE DETERMINED AT DATUM H. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.

- DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MIL	LIMETE	ERS		INCHES	}	
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α			1.10			0.043	
A1	0.00		0.10	0.000		0.004	
A2	0.70	0.90	1.00	0.027	0.035	0.039	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.08	0.15	0.22	0.003	0.006	0.009	
D	1.80	2.00	2.20	0.070	0.078	0.086	
E	2.00	2.10	2.20	0.078	0.082	0.086	
E1	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0	.026 BS	С	
L	0.26	0.36	0.46	0.010	0.014	0.018	
L2		0.15 BS	C	0.006 BSC			
aaa		0.15		0.006			
bbb	0.30				0.012		
ccc	0.10 0.0				0.004		
ddd		0.10			0.004		

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

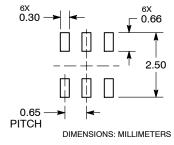
= Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

- \*Date Code orientation and/or position may vary depending upon manufacturing location.
- \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13: PIN 1. ANODE 2. N/C 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 14: PIN 1. VREF 2. GND 3. GND 4. IOUT 5. VEN 6. VCC	STYLE 15: PIN 1. ANODE 1 2. ANODE 2 3. ANODE 3 4. CATHODE 3 5. CATHODE 2 6. CATHODE 1	STYLE 16: PIN 1. BASE 1 2. EMITTER 2 3. COLLECTOR 2 4. BASE 2 5. EMITTER 1 6. COLLECTOR 1	STYLE 17: PIN 1. BASE 1 2. EMITTER 1 3. COLLECTOR 2 4. BASE 2 5. EMITTER 2 6. COLLECTOR 1	STYLE 18: PIN 1. VIN1 2. VCC 3. VOUT2 4. VIN2 5. GND 6. VOUT1
STYLE 19: PIN 1. I OUT 2. GND 3. GND 4. V CC 5. V EN 6. V REF	STYLE 20: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 21: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. N/C 6. CATHODE 1	STYLE 22: PIN 1. D1 (i) 2. GND 3. D2 (i) 4. D2 (c) 5. VBUS 6. D1 (c)	STYLE 23: PIN 1. Vn 2. CH1 3. Vp 4. N/C 5. CH2 6. N/C	STYLE 24: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 25: PIN 1. BASE 1 2. CATHODE 3. COLLECTOR 2 4. BASE 2 5. EMITTER 6. COLLECTOR 1	STYLE 26: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1	STYLE 27: PIN 1. BASE 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. EMITTER 2 6. COLLECTOR 2	STYLE 28: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 29: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE/ANODE 6. CATHODE	STYLE 30: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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